



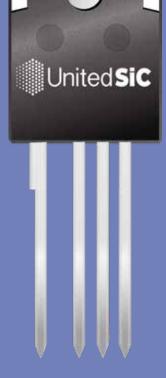
High Performance SiC FETs, JFETs and Schottky Diodes

Key Features

- Multiple V_{DS} options: 650/750/900/1200/1700V
- Lowest R_{DS(on)}
 - 7mΩ @ 650V
 - 9mΩ @ 1200V
- Gen 4 SiC FETs (UJ4C Series)
 - 750V, $18m\Omega$ and $60m\Omega$ options
 - Best-in-class R_{DS(on)} x Area delivers lowest conduction losses
 - Improves the Q_{rr} and E_{on}/E_{off} losses at a given RDS(on)
 - Reduces both C_{oss(er)}/E_{oss} and C_{oss(tr)}
- High performance cascode configuration
- Excellent body diode (Vf < 2V)
- Drive with any Si and/or SiC gate drive voltage
- Superior thermal performance
- Integrated ESD and gate protection
- Industry standard packages, including Kelvin source
- Majority of devices are AEC-Q101 qualified

End Applications

- Electric Vehicles
- Battery Chargers
- Telecom and Server PSU
- Circuit Protection
- Solar Inverters
- Energy Storage
- Motor drives

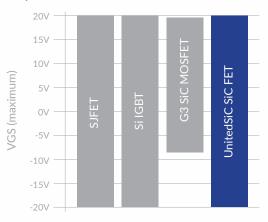




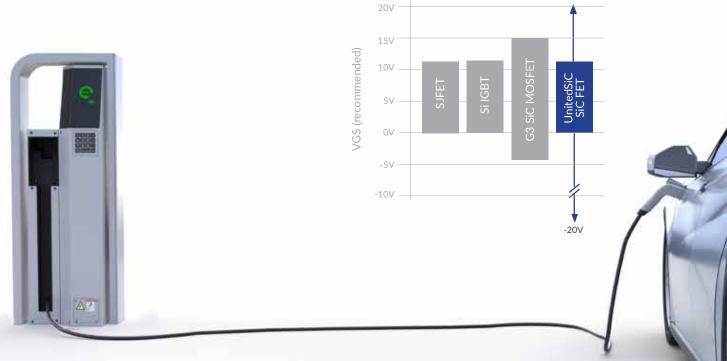
Flexible Design Without Changing Gate Drive Voltage

- Replaces Si IGBTs, Si FETs, SiC MOSFETs or Si Superjunction devices
 - SiC FET design guidelines available to support successful upgrade
- Innovative cascode configuration enables Si and SiC gate voltage compatibility
- Integrated clamping diode protects gates from |20V| with built-in ESD protection

Superior Gate and ESD Protection



12V/0V Operation Simplifies Upgrading



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SiC FETs

UF3C/UF3SC/UJ3C/UJ4C Series Selector Guide













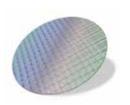
				- //	***				
Volt.	R _{DS(on)} (mΩ) at 25°C	R _D S(on) (mΩ) at 125°C	Generation	TO-247-3L	TO-247-4L	D2PAK-3L	TO-220-3L	D2PAK-7L	DFN 8X8
650V	6.7	8.8	Gen 3 Fast		UF3SC065007K4S				
	27	35	Gen 3 Fast	UF3C065030K3S ⁽¹⁾	UF3C065030K4S	UF3C065030B3 ⁽¹⁾	UF3C065030T3S (1)	UF3SC065030B7S	
			Gen 3	UJ3C065030K3S		UJ3C065030B3	UJ3C065030T3S		
	34	48	Gen 3 Fast						UF3SC065030D8S
	42	59	Gen 3 Fast	UF3C065040K3S	UF3C065040K4S	UF3C065040B3	UF3C065040T3S	UF3SC065040B7S	
	45	67	Gen 3 Fast						UF3SC065040D8S
	80	111	Gen 3 Fast	UF3C065080K3S ⁽¹⁾	UF3C065080K4S	UF3C065080B3 ⁽¹⁾	UF3C065080T3S ⁽¹⁾	UF3C065080B7S	
			Gen 3	UJ3C065080K3S		UJ3C065080B3	UJ3C065080T3S		
750V	18	23	Gen 4	UJ4C075018K3S	UJ4C075018K4S				
	58	74	Gen 4	UJ4C075060K3S	UJ4C075060K4S				
1200V	8.6	13.5	Gen 3 Fast		UF3SC120009K4S				
	16	25	Gen 3 Fast	UF3SC120016K3S	UF3SC120016K4S				
	35	56	Gen 3 Fast	UF3C120040K3S	UF3C120040K4S			UF3SC120040B7S	
			Gen 3	UJ3C120040K3S					
	70	111	Gen 3	UJ3C120070K3S					
	80	132	Gen 3 Fast	UF3C120080K3S	UF3C120080K4S			UF3C120080B7S	
			Gen 3	UJ3C120080K3S					
	150	254	Gen 3 Fast		UF3C120150K4S			UF3C120150B7S	
			Gen 3	UJ3C120150K3S					
	410	775	Gen 3 Fast	UF3C120400K3S					
1700V	410	775	Gen 3 Fast	UF3C170400K3S					

Notes:

⁽¹⁾ Q(rr) for UF3C FAST device lower than equivalent UJ3C device All data represents current information as of June, 2021.



SiC JFETsUJ3N/UF3N Series Selector Guide





Voltage	R _{DS(on)} (mΩ)	I _D max (A) at 25°C	Generation	Wafer (Contact Sales)	TO-247-3L
	1100	3.9	Gen 3	UJ3N1701K2	
1700V	400	8 (1)	Gen 3 Fast	UF3N170400	
	140	20 (1)	Gen 3 Fast	UF3N120140	
	70	33.5	Gen 3	UJ3N120070	UJ3N120070K3S
1200V	66	34	Gen 3		UJ3N120065K3S
	35	63	Gen 3	UJ3N120035	UJ3N120035K3S
0001	735	4 (1)	Gen 3 Fast	UF3N090800	
900V	330	8 (1)	Gen 3 Fast	UF3N090350	
	580	4 (1)	Gen 3 Fast	UF3N065600	
	265	8 (1)	Gen 3 Fast	UF3N065300	
650V	80	32	Gen 3	UJ3N065080	UJ3N065080K3S
	25	85	Gen 3	UJ3N065025	UJ3N065025K3S

Notes:

(1) Limited by bondwire.

Advanced information for wafer parts, please refer to product datasheet for specifications.



SiC Schottky Diodes

UJ3D Series Selector Guide







	1				
Voltage	Current Rating	Generation	TO-220-2L	TO-247-3L	TO-247-2L
1700V	25A	Gen 3			UJ3D1725K2
	2A	Gen 3	UJ3D1202TS		
	5A	Gen 3	UJ3D1205TS		
	2 x 5A	Gen 3		UJ3D1210KSD	
1200V	10A	Gen 3	UJ3D1210TS	UJ3D1210KS	UJ3D1210K2
	2 x 10A	Gen 3		UJ3D1220KSD	
	20A	Gen 3			UJ3D1220K2
	50A	Gen 3		UJ3D1250K	UJ3D1250K2
	4A	Gen 3	UJ3D06504TS		
	6A	Gen 3	UJ3D06506TS		
	8A	Gen 3	UJ3D06508TS		
	10A	Gen 3	UJ3D06510TS		
650V	12A	Gen 3	UJ3D06512TS		
030 v	16A	Gen 3	UJ3D06516TS		
	2 x 10A	Gen 3		UJ3D06520KSD	
	20A	Gen 3	UJ3D06520TS		
	30A	Gen 3	UJ3D06530TS		
	2 x 30A	Gen 3		UJ3D06560KSD	

Note(s):

For all die inquiries, contact sales@unitedsic.com All data represents current information as of June, 2021.



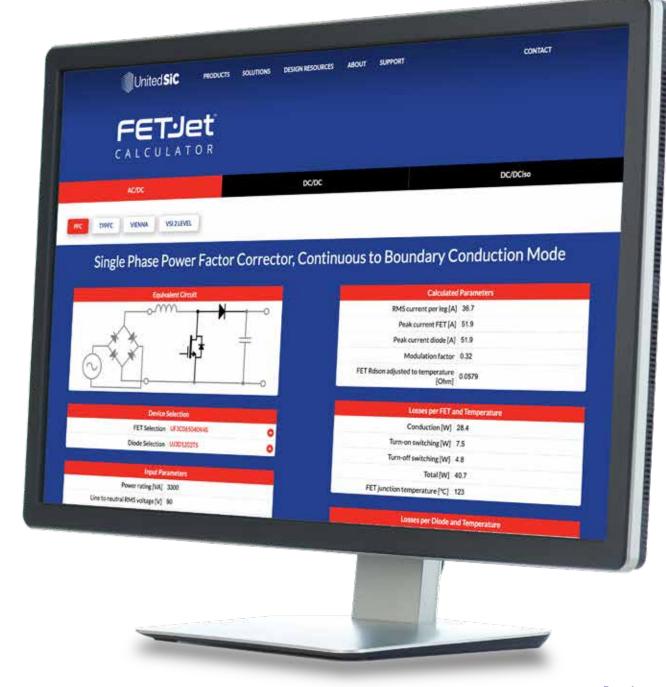


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